

### **FEATURES**

Epitaxial planar die construction. Ideal for low power amplification and switching.



# **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
MMDT3904	SOT-363	K6N	3000



## MAXIMUM RATINGS (Ta=25 unless otherwise noted)

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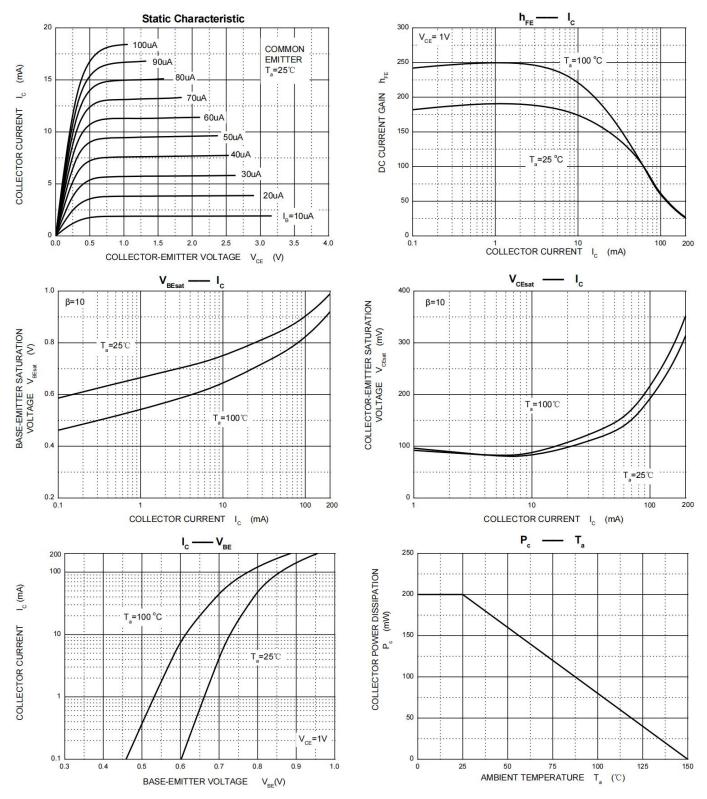
Symbol	Parameter	Value	Unit
$V_{\text{CBO}}$	Collector-Base Voltage	60	V
$V_{\text{CEO}}$	Collector-Emitter Voltage	40	V
$V_{EBO}$	Emitter-Base Voltage	6	V
Ic	Collector Current	200	mA
Pc	Collector Power Dissipation	200	mW
R <sub>⊝JA</sub>	Thermal Resistance From Junction To Ambient	625	°C/W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction And Storage Temperature Range	-55~+150	${\mathbb C}$

## **ELECTRICAL CHARACTERISTICS(Ta=25** unless otherwise noted)

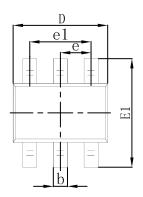
Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =10μΑ, I <sub>E</sub> =0	60			V
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =1mA, I <sub>B</sub> =0	40			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =10μΑ, I <sub>C</sub> =0	6			V
I <sub>CEX</sub>	Collector cut-off current	V <sub>CE</sub> =30V, V <sub>EB(off)</sub> =3V			50	nA
Ісво	Collector cut-off current	V <sub>CB</sub> =30V, I <sub>E</sub> =0			50	nA
I <sub>EBO</sub>	Emitter cut-off current	$V_{EB}$ =5 $V$ , $I_{C}$ =0			50	nA
h <sub>FE</sub> (1)	DC current gain(1)	V <sub>CE</sub> =1V, I <sub>C</sub> =100μA	40			
h <sub>FE</sub> (2)	DC current gain(2)	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA	70			
h <sub>FE</sub> (3)	DC current gain(3)	V <sub>CE</sub> =1V, I <sub>C</sub> =10mA	100		300	
h <sub>FE</sub> (4)	DC current gain(4)	V <sub>CE</sub> =1V, I <sub>C</sub> =50mA	60			
h <sub>FE</sub> (5)	DC current gain(5)	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	30			
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Collector-emitter saturation voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.2	V
V <sub>CE(sat)</sub>	Collector-entitler saturation voltage	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			0.3	V
V	Base-emitter saturation voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA	0.65		0.85	V
V <sub>BE(sat)</sub>	Base-emitter saturation voitage	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA			0.95	V
f⊤	Transition frequency	V <sub>CE</sub> =20V, I <sub>C</sub> =10mA, f=100MHz	300			MHz
Cob	Collector output capacitance	$V_{CB}$ =5 $V$ , $I_E$ =0, $f$ =1 $MHz$			4	pF
NF	Noise figure	VCE=5V,lc=0.1mA,f=1kHz,Rg=1K $\Omega$	E=5V,lc=0.1mA,f=1kHz,Rg=1KΩ		5	dB
t <sub>d</sub>	Delay time	V <sub>CC</sub> =3V, V <sub>BE(off)</sub> =0.5V,			35	ns
t <sub>r</sub>	Rise time	I <sub>C</sub> =10mA, I <sub>B1</sub> =I <sub>B2</sub> =1mA			35	ns
ts	Storage time	V <sub>CC</sub> =3V, I <sub>C</sub> =10mA,			200	ns
t <sub>f</sub>	Fall time	I <sub>B1</sub> =I <sub>B2</sub> =1mA			50	ns

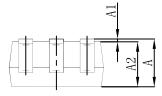


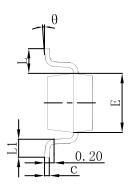
# **Typical Characteristics**



## **SOT-363 Package Outline Dimensions**

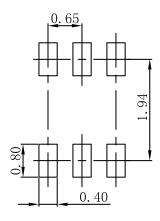






Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Syllibol	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150	0.350	0.006	0.014	
С	0.100	0.150	0.004	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.400	0.085	0.094	
е	0.650 TYP		0.026 TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

## **SOT-363 Suggested Pad Layout**



#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.



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